
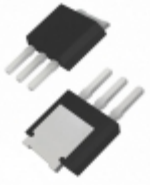




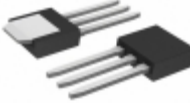


	<h2 style="color: red;">NTD78N03-35G</h2>
	<p>Hersteller-Teilenummer: NTD78N03-35G</p> <p>Hersteller / Marke: AMI Semiconductor / ON Semiconductor</p> <p>Teil der Beschreibung: MOSFET N-CH 25V 11.4A IPAK</p> <p>Datenblätter:  NTD78N03-35G.pdf</p> <p>RoHs Status: Bleifrei / RoHS-konform</p> <p>Lagerzustand: New original, 5661 pcs Stock Available.</p> <p>Liefern von: Hong Kong</p> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p>
<p>Image may be representation. See specs for product details.</p>	

Spezifikationen

Teilenummer	NTD78N03-35G
Hersteller	AMI Semiconductor / ON Semiconductor
Beschreibung	MOSFET N-CH 25V 11.4A IPAK
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs ,
Teilstatus	5661 pcs Stock
Serie	-
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 175°C (TJ)
Befestigungsart	Through Hole
Verpackung / Gehäuse	TO-251-3 Stub Leads, IPak
Supplier Device-Gehäuse	I-Pak
Verlustleistung (max)	1.4W (Ta), 64W (Tc)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	25V
Strom - Ununterbrochener Abfluss (Id) bei 25 °C	11.4A (Ta), 78A (Tc)
Rds On (Max) @ Id, Vgs	6 mOhm @ 78A, 10V
VGS (th) (Max) @ Id	3V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	35nC @ 4.5V
Eingabekapazität (Ciss) (Max) @ Vds	2250pF @ 12V
Verpackung	Tube

NTD78N03-35G ist neu im Original, Suche NTD78N03-35G Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie NTD78N03-35G AMI Semiconductor / ON Semiconductor mit Garantie und Vertrauen. Anfrage NTD78N03-35G: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>NTD78N03-035 AMI Semiconductor / ON Semiconductor MOSFET N-CH 25V 11.4A IPAK</p>	 <p>NTD78N03R-1G ON NTD78N03R-1G ON</p>	 <p>NTD78N03R-001 VB NTD78N03R-001 VB</p>	 <p>NTD78N03RT4G ON NTD78N03RT4G ON</p>
 <p>NTD78N03-1 ON NTD78N03-1 ON</p>	 <p>NTD78N03-001 AMI Semiconductor / ON Semiconductor MOSFET N-CH 25V 11.4A IPAK</p>	 <p>NTD78N03RG ON NTD78N03RG ON</p>	 <p>NTD78N03 AMI Semiconductor / ON Semiconductor MOSFET N-CH 25V 11.4A DPAK</p>

heiße Teile

Mehr

NTD65N03R-035	NTD65N03R-1G	NTD65N03R-35G	NTD65N03RG	NTD65N03RT4G
NTD6600G	NTD6600N	NTD6600N-001	NTD6600N-1G	NTD6600NT4
NTD6600NT4G	NTD70N03	NTD70N03R	NTD70N03R-001	NTD70N03R-1
NTD70N03R-1G	NTD70N03RG	NTD70N03RT4	NTD70N03RT4G	NTD70N03TR4
NTD78N03	NTD78N03-001	NTD78N03-035	NTD78N03-1	NTD78N03-1G
NTD78N03R-001	NTD78N03R-1G	NTD78N03RT4G	NTD78N03T4	NTD78N03T4G
NTD80N02	NTD80N02-001	NTD80N02-1	NTD80N02-1G	NTD80N02G
NTD80N02T4	NTD80N02T4G	NTD85N02-1G	NTD85N02R	NTD85N02R-001
NTD85N02R-1	NTD85N02R-1G	NTD85N02R14	NTD85N02RG	NTD85N02RT4G
NTD85N02T4G	NTD95N02-001	NTD95N02-1G	NTD95N02R	NTD95N02R-1G

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